Lead-free Green

DMMT3906W

40V MATCHED PAIR PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- BV_{CEO} > -40V
- I_C = -200mA High Collector Current
- Pair of PNP Transistors That Are Intrinsically Matched (Note 1)
- 2% Matching on Current Gain (h_{FE})
- 2mV Matching on Base-Emitter Voltage (V_{BE})
- Fully Internally Isolated in a Small Surface Mount Package
- **Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)**
- **Halogen and Antimony Free. "Green" Device (Note 4)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 5)**

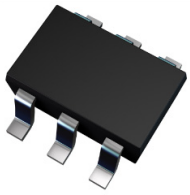
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, “Green” Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Finish. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.006 grams (approximate)

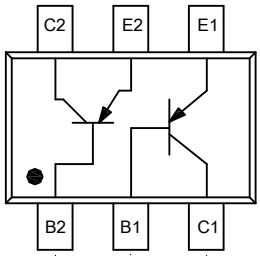
Applications

- Current Mirrors
- Differential and Instrumentation Amplifiers
- Comparators

SOT363



Top View



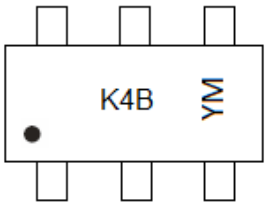
Device Schematic and Pin-Out
Top View

Ordering Information (Note 4 & 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DMMT3906W-7-F	AEC-Q101	K4B	7	8	3,000
DMMT3906WQ-7-F	Automotive	K4B	7	8	3,000

Notes:
1. Intrinsically matched pair as this is built with adjacent die from the same wafer.
2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
3. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated’s definitions of Halogen- and Antimony-free, "Green" and Lead-free.
4. Halogen- and Antimony-free "Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
5. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
6. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K4B = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: B = 2014)
M = Month (ex: 2 = February)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-200	mA

Thermal Characteristics – Total Device (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7) Total Device	P_D	200	mW
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Note: 7. For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state.
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics – Total Device

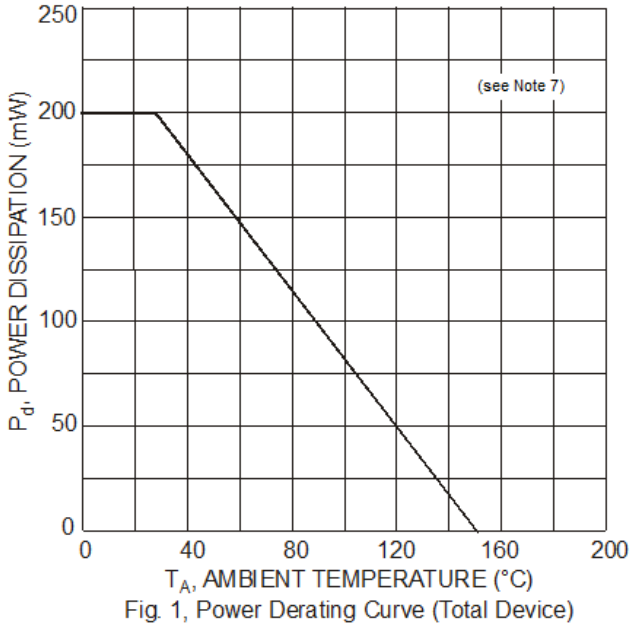


Fig. 1, Power Derating Curve (Total Device)

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Electrical Characteristics (@T_A = +25°C unless otherwise specified)

Characteristic	Symbol	Min	TYP	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	-40	—	—	V	I_C = -100μA, I_E = 0
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-40	—	—	V	I_C = -1.0mA, I_B = 0
Emitter-Base Breakdown Voltage	BV_{EBO}	-5.0	—	—	V	I_E = -100μA, I_C = 0
Collector Cutoff Current	I_{CEX}	—	—	-50	nA	V_{CE} = -30V, $V_{EB(OFF)}$ = 3.0V
Base Cutoff Current	I_{BL}	—	—	-50	nA	V_{CE} = -30V, $V_{EB(OFF)}$ = 3.0V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h_{FE}	60 80 100 60 30	—	— — 300 — —	—	I_C = -100μA, V_{CE} = -1.0V I_C = -1.0mA, V_{CE} = -1.0V I_C = -10mA, V_{CE} = -1.0V I_C = -50mA, V_{CE} = - 1.0V I_C = -100mA, V_{CE} = -1.0V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	-250 -400	mV	I_C = -10mA, I_B = -1.0mA I_C = -50mA, I_B = -5.0mA
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	0.65 —	—	-850 -950	mV	I_C = -10mA, I_B = -1.0mA I_C = -50mA, I_B = -5.0mA
MATCHING CHARACTERISTICS						
DC Current Gain Matching (Note 10)	h_{FE1} / h_{FE2}	—	1	2	%	I_C = -2mA, V_{CE} = -5V
Base-Emitter Voltage Matching (Note 11)	V_{BE1} - V_{BE2}	—	1	2	mV	I_C = -2mA, V_{CE} = -5V
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(SAT)1}$ / $V_{CE(SAT)2}$	—	1	2	%	I_C = -10mA, I_B = -1.0mA
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(SAT)1}$ / $V_{BE(SAT)2}$	—	1	2	%	I_C = -10mA, I_B = -1.0mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C_{obo}	—	—	4.5	pF	V_{CB} = -5.0V, f = 1.0MHz, I_E = 0
Input Capacitance	C_{ibo}	—	—	10.0	pF	V_{EB} = -0.5V, f = 1.0MHz, I_C = 0
Input Impedance	h_{ie}	2.0	—	12	kΩ	V_{CE} = 10V, I_C = 1.0mA, f = 1.0kHz
Voltage Feedback Ratio	h_{re}	0.1	—	10	x 10^{-4}	
Small Signal Current Gain	h_{fe}	100	—	400	—	
Output Admittance	h_{oe}	3.0	—	60	μS	
Current Gain-Bandwidth Product	f_T	250	—	—	MHz	V_{CE} = -20V, I_C = -10mA, f = 100MHz
Noise Figure	NF	—	—	4.0	dB	V_{CE} = -5.0V, I_C = -100μA, R_S = 1.0kΩ, f = 1.0kHz
SWITCHING CHARACTERISTICS						
Delay Time	t_d	—	—	35	ns	V_{CC} = -3.0V, I_C = -10mA, $V_{BE(off)}$ = 0.5V, I_{B1} = -1.0mA
Rise Time	t_r	—	—	35	ns	
Storage Time	t_s	—	—	225	ns	V_{CC} = -3.0V, I_C = -10mA, I_{B1} = I_{B2} = -1.0mA
Fall Time	t_f	—	—	75	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.
10. Is the ratio of one transistor compared to the other transistor.
11. V_{BE1} - V_{BE2} is the absolute difference of one transistor compared to the other transistor.

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Typical Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

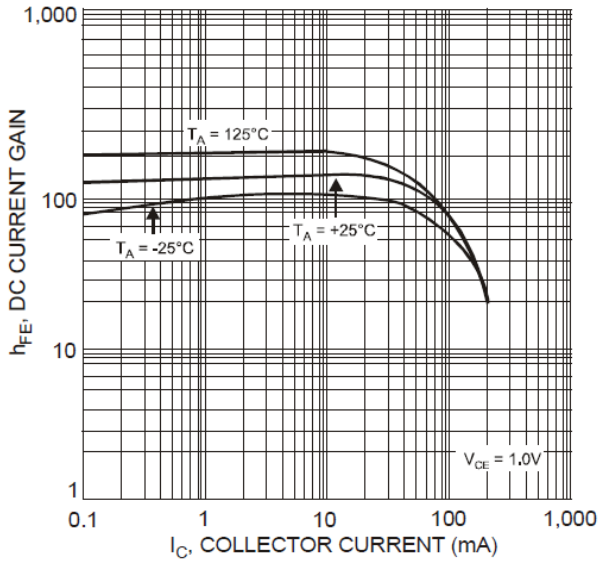


Fig. 3, Typical DC Current Gain vs. Collector Current

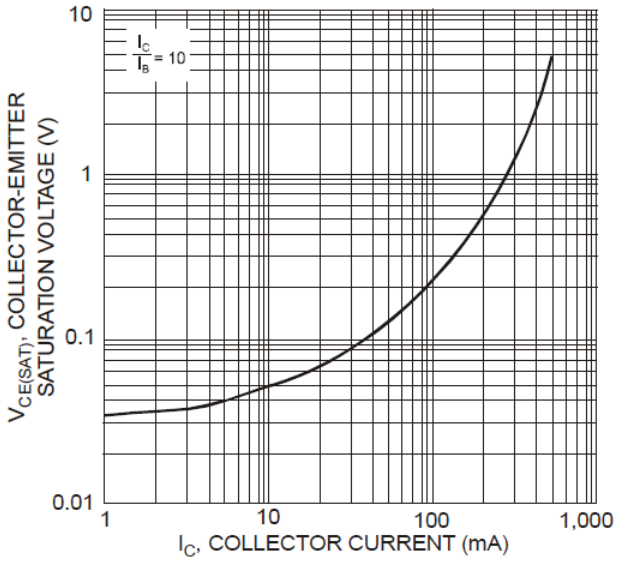


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

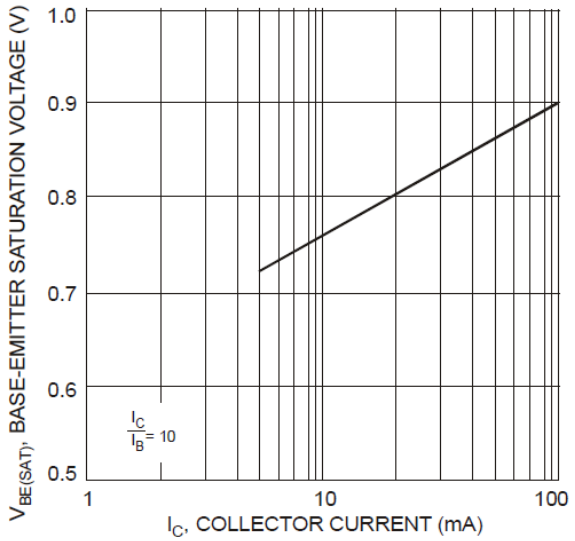


Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

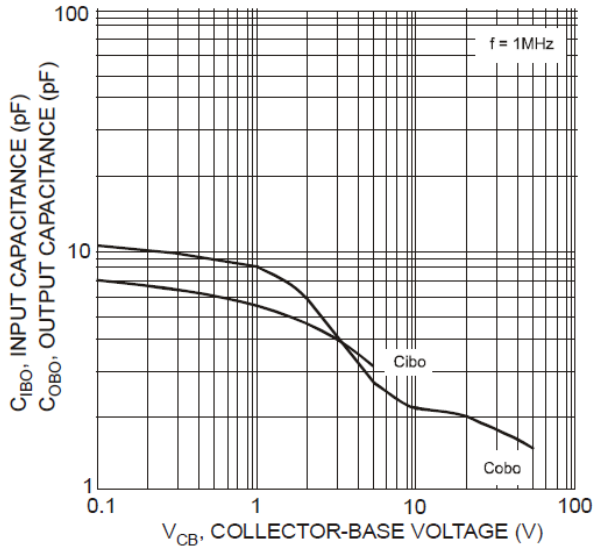
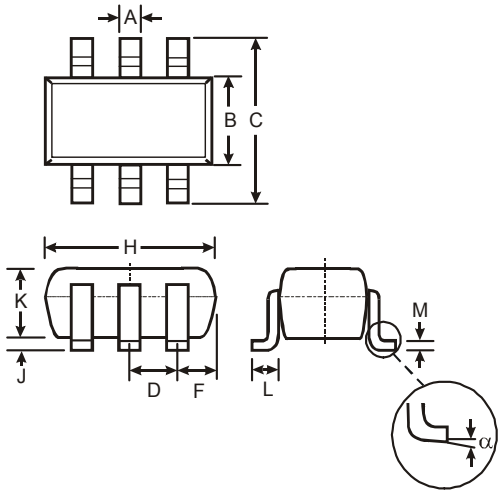


Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage

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Package Outline Dimensions

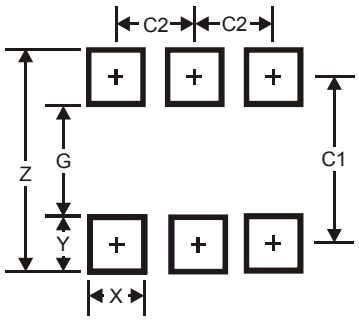
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT363			
Dim	**Min**	**Max**	**Typ**
A	0.10	0.30	0.25
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	0.65 Typ		
F	0.40	0.45	0.425
H	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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